## NSN 5961-01-356-1380



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-356-1380 **Inclosure Material:** Metal **Overall Length:** Between 1.290 inches and 1.300 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.249 inches **Overall Width:** Between 0.535 inches and 0.545 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-254aa **Mounting Method: Terminal Features Provided:** Electrostatic sensitive and hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 24.00 amperes drain current **Power Rating Per Characteristic:** 125.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Nuclear hardness critical item **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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